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#### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "[Embedded - Microcontrollers](#)"

##### Details

Product Status	Active
Core Processor	S08
Core Size	8-Bit
Speed	20MHz
Connectivity	I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	18
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SOIC (0.295", 7.50mm Width)
Supplier Device Package	20-SOIC
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s08pa8avwj">https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s08pa8avwj</a>

- Input/Output
  - Up to 37 GPIOs including one output-only pin
  - One 8-bit keyboard interrupt module (KBI)
  - Two true open-drain output pins
  - Four, ultra-high current sink pins supporting 20 mA source/sink current
- Package options
  - 44-pin LQFP
  - 32-pin LQFP
  - 20-pin SOIC; 20-pin TSSOP
  - 16-pin TSSOP

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This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either  $V_{SS}$  or  $V_{DD}$ ) or the programmable pullup resistor associated with the pin is enabled.

Symbol	Description	Min.	Max.	Unit
$V_{DD}$	Supply voltage	-0.3	6.0	V
$I_{DD}$	Maximum current into $V_{DD}$	—	120	mA
$V_{DIO}$	Digital input voltage (except $\overline{RESET}$ , EXTAL, XTAL, or true open drain pin PTA2 and PTA3)	-0.3	$V_{DD} + 0.3$	V
	Digital input voltage (true open drain pin PTA2 and PTA3)	-0.3	6	V
$V_{AIO}$	Analog <sup>1</sup> , $\overline{RESET}$ , EXTAL, and XTAL input voltage	-0.3	$V_{DD} + 0.3$	V
$I_D$	Instantaneous maximum current single pin limit (applies to all port pins)	-25	25	mA
$V_{DDA}$	Analog supply voltage	$V_{DD} - 0.3$	$V_{DD} + 0.3$	V

1. All digital I/O pins, except open-drain pin PTA2 and PTA3, are internally clamped to  $V_{SS}$  and  $V_{DD}$ . PTA2 and PTA3 is only clamped to  $V_{SS}$ .

## 5 General

### 5.1 Nonswitching electrical specifications

#### 5.1.1 DC characteristics

This section includes information about power supply requirements and I/O pin characteristics.

Table 2. DC characteristics

Symbol	C	Descriptions		Min	Typical <sup>1</sup>	Max	Unit
—	—	Operating voltage		—	—	5.5	V
$V_{OH}$	C	Output high voltage	All I/O pins, standard-drive strength	5 V, $I_{load} = -5 \text{ mA}$	$V_{DD} - 0.8$	—	V
	C			3 V, $I_{load} = -2.5 \text{ mA}$	$V_{DD} - 0.8$	—	V
	C	High current drive pins, high-drive strength <sup>2</sup>		5 V, $I_{load} = -20 \text{ mA}$	$V_{DD} - 0.8$	—	V
	C			3 V, $I_{load} = -10 \text{ mA}$	$V_{DD} - 0.8$	—	V

Table continues on the next page...

Table 2. DC characteristics (continued)

Symbol	C	Descriptions			Min	Typical <sup>1</sup>	Max	Unit
$I_{OHT}$	D	Output high current	Max total $I_{OH}$ for all ports	5 V	—	—	-100	mA
				3 V	—	—	-50	
$V_{OL}$	C	Output low voltage	All I/O pins, standard-drive strength	5 V, $I_{load} = 5$ mA	—	—	0.8	V
	C			3 V, $I_{load} = 2.5$ mA	—	—	0.8	V
	C		High current drive pins, high-drive strength <sup>2</sup>	5 V, $I_{load} = 20$ mA	—	—	0.8	V
	C			3 V, $I_{load} = 10$ mA	—	—	0.8	V
$I_{OLT}$	D	Output low current	Max total $I_{OL}$ for all ports	5 V	—	—	100	mA
				3 V	—	—	50	
$V_{IH}$	P	Input high voltage	All digital inputs	$V_{DD} > 4.5V$	$0.70 \times V_{DD}$	—	—	V
	C			$V_{DD} > 2.7V$	$0.75 \times V_{DD}$	—	—	
$V_{IL}$	P	Input low voltage	All digital inputs	$V_{DD} > 4.5V$	—	—	$0.30 \times V_{DD}$	V
	C			$V_{DD} > 2.7V$	—	—	$0.35 \times V_{DD}$	
$V_{hys}$	C	Input hysteresis	All digital inputs	—	$0.06 \times V_{DD}$	—	—	mV
$ I_{In} $	P	Input leakage current	All input only pins (per pin)	$V_{IN} = V_{DD}$ or $V_{SS}$	—	0.1	1	$\mu A$
$ I_{OZL} $	P	Hi-Z (off-state) leakage current	All input/output (per pin)	$V_{IN} = V_{DD}$ or $V_{SS}$	—	0.1	1	$\mu A$
$ I_{OZTOT} $	C	Total leakage combined for all inputs and Hi-Z pins	All input only and I/O	$V_{IN} = V_{DD}$ or $V_{SS}$	—	—	2	$\mu A$
$R_{PU}$	P	Pullup resistors	All digital inputs, when enabled (all I/O pins other than PTA2 and PTA3)	—	30.0	—	50.0	k $\Omega$
$R_{PU}^3$	P	Pullup resistors	PTA2 and PTA3 pin	—	30.0	—	60.0	k $\Omega$
$I_{IC}$	D	DC injection current <sup>4, 5, 6</sup>	Single pin limit	$V_{IN} < V_{SS}$ , $V_{IN} > V_{DD}$	-0.2	—	2	mA
			Total MCU limit, includes sum of all stressed pins		-5	—	25	
$C_{In}$	C	Input capacitance, all pins		—	—	—	7	pF
$V_{RAM}$	C	RAM retention voltage		—	2.0	—	—	V

1. Typical values are measured at 25 °C. Characterized, not tested.
2. Only PTB4, PTB5, PTD0, PTD1 support ultra high current output.
3. The specified resistor value is the actual value internal to the device. The pullup value may appear higher when measured externally on the pin.
4. All functional non-supply pins, except for , are internally clamped to  $V_{SS}$  and  $V_{DD}$ .
5. Input must be current-limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the large one.

6. Power supply must maintain regulation within operating  $V_{DD}$  range during instantaneous and operating maximum current conditions. If the positive injection current ( $V_{In} > V_{DD}$ ) is higher than  $I_{DD}$ , the injection current may flow out of  $V_{DD}$  and could result in external power supply going out of regulation. Ensure that external  $V_{DD}$  load will shunt current higher than maximum injection current when the MCU is not consuming power, such as no system clock is present, or clock rate is very low (which would reduce overall power consumption).

**Table 3. LVD and POR Specification**

Symbol	C	Description	Min	Typ	Max	Unit
$V_{POR}$	D	POR re-arm voltage <sup>1, 2</sup>	1.5	1.75	2.0	V
$V_{LVDH}$	C	Falling low-voltage detect threshold - high range (LVDV = 1) <sup>3</sup>	4.2	4.3	4.4	V
$V_{LVW1H}$	C	Falling low-voltage warning threshold - high range	4.3	4.4	4.5	V
$V_{LVW2H}$	C	Level 1 falling (LVWV = 00)	4.5	4.5	4.6	V
$V_{LVW3H}$	C	Level 2 falling (LVWV = 01)	4.6	4.6	4.7	V
$V_{LVW4H}$	C	Level 3 falling (LVWV = 10)	4.7	4.7	4.8	V
$V_{HYSH}$	C	Level 4 falling (LVWV = 11)	—	100	—	mV
$V_{LVDL}$	C	High range low-voltage detect/warning hysteresis	2.56	2.61	2.66	V
$V_{LVDW1L}$	C	Falling low-voltage detect threshold - low range (LVDV = 0)	2.62	2.7	2.78	V
$V_{LVDW2L}$	C	Level 1 falling (LVWV = 00)	2.72	2.8	2.88	V
$V_{LVDW3L}$	C	Level 2 falling (LVWV = 01)	2.82	2.9	2.98	V
$V_{LVDW4L}$	C	Level 3 falling (LVWV = 10)	2.92	3.0	3.08	V
$V_{HYSNL}$	C	Level 4 falling (LVWV = 11)	—	40	—	mV
$V_{HYSWL}$	C	Low range low-voltage warning hysteresis	—	80	—	mV
$V_{BG}$	P	Low range low-voltage detect hysteresis	1.14	1.16	1.18	V

1. Maximum is highest voltage that POR is guaranteed.
2. POR ramp time must be longer than 20us/V to get a stable startup.
3. Rising thresholds are falling threshold + hysteresis.
4. Voltage factory trimmed at  $V_{DD} = 5.0$  V, Temp = 25 °C

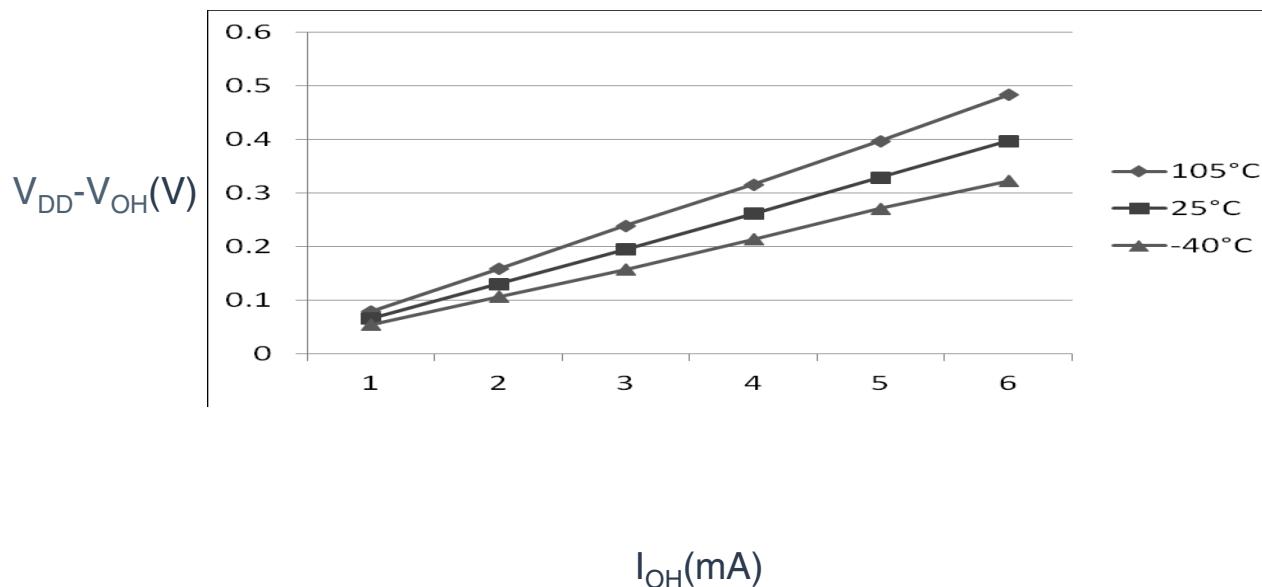


Figure 1. Typical  $I_{OH}$  Vs.  $V_{DD} - V_{OH}$  (standard drive strength) ( $V_{DD} = 5$  V)

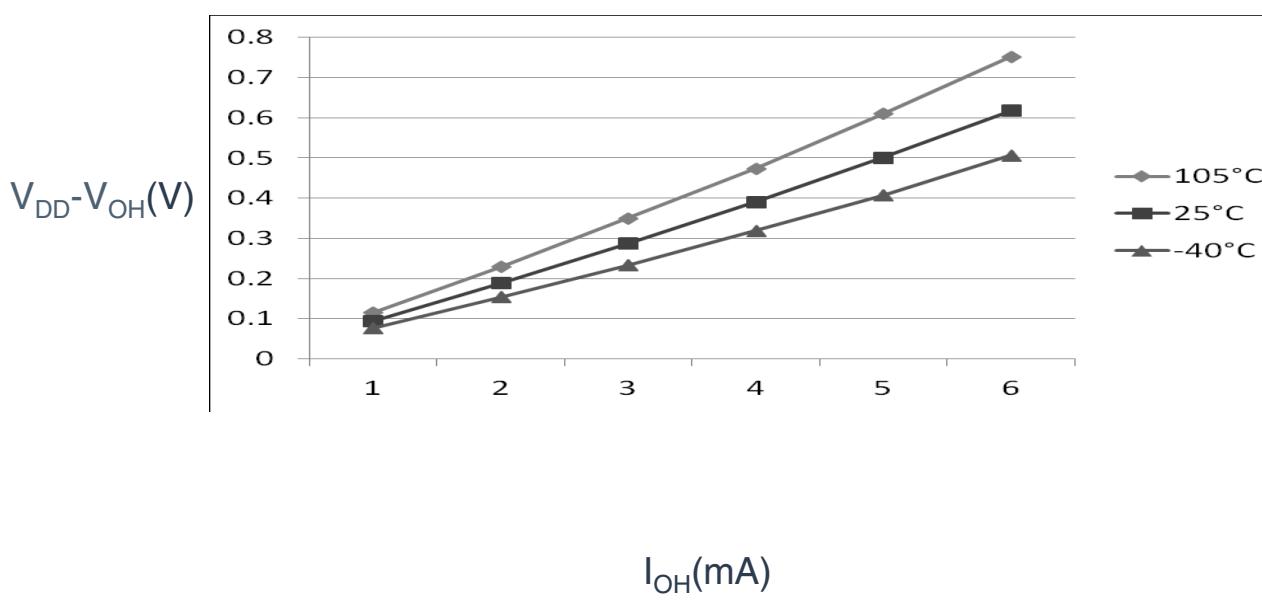


Figure 2. Typical  $I_{OH}$  Vs.  $V_{DD} - V_{OH}$  (standard drive strength) ( $V_{DD} = 3$  V)

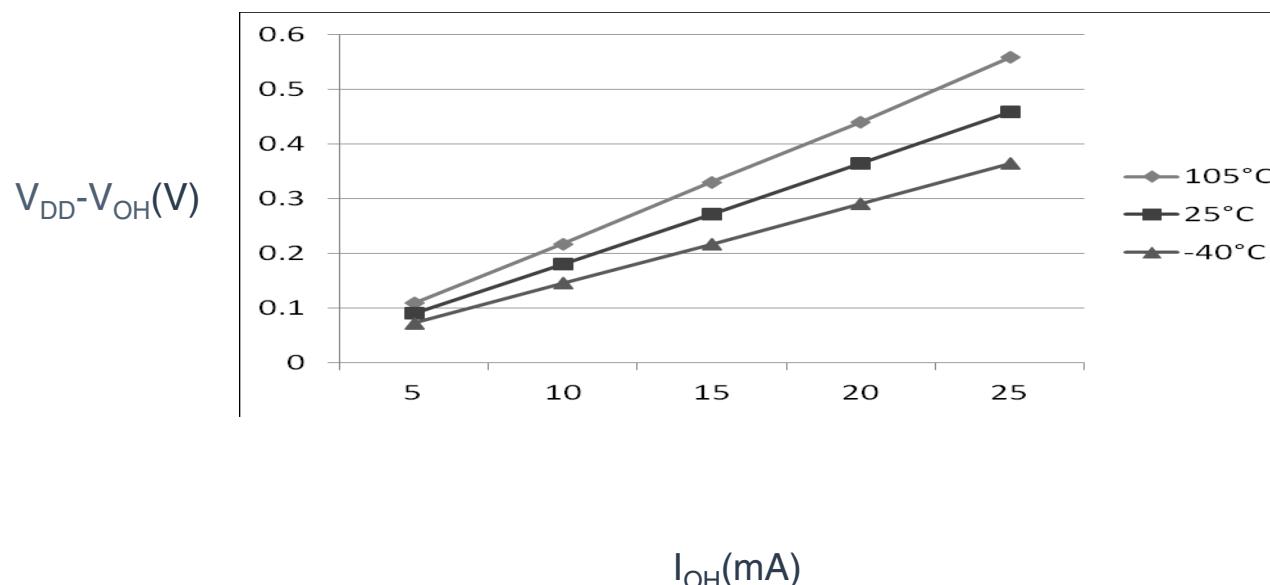


Figure 3. Typical  $I_{OH}$  Vs.  $V_{DD} - V_{OH}$  (high drive strength) ( $V_{DD} = 5$  V)

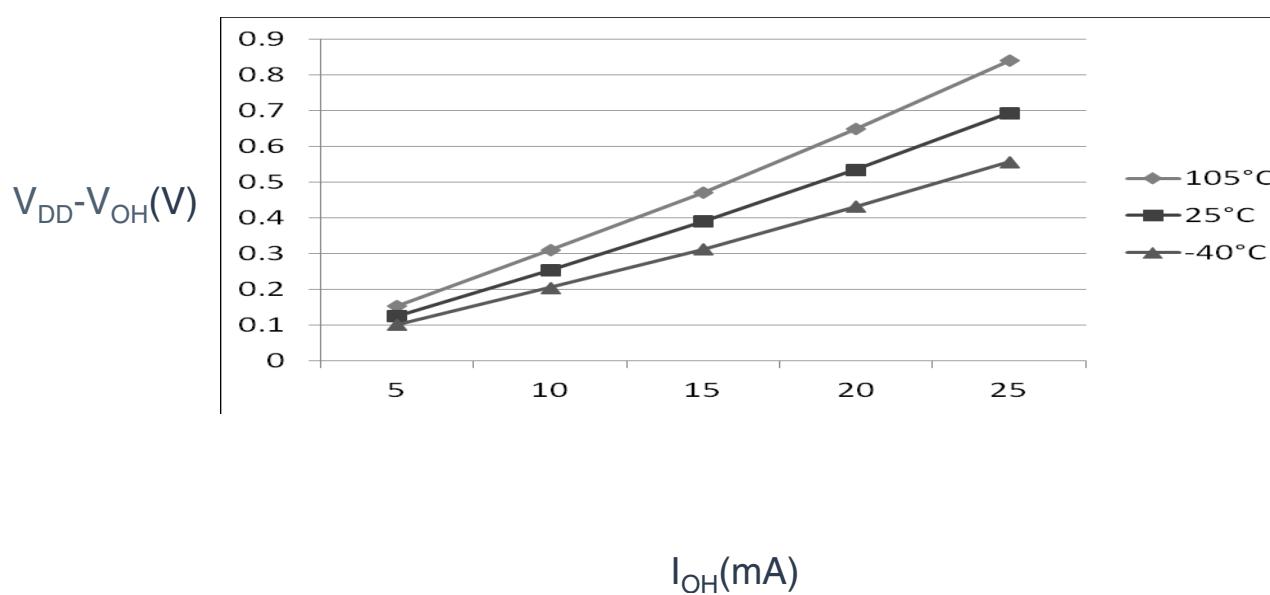


Figure 4. Typical  $I_{OH}$  Vs.  $V_{DD} - V_{OH}$  (high drive strength) ( $V_{DD} = 3$  V)

## 5.1.2 Supply current characteristics

This section includes information about power supply current in various operating modes.

**Table 4. Supply current characteristics**

Num	C	Parameter	Symbol	Bus Freq	V <sub>DD</sub> (V)	Typical <sup>1</sup>	Max	Unit	Temp
1	C	Run supply current FEI mode, all modules on; run from flash	RI <sub>DD</sub>	20 MHz	5	7.60	—	mA	-40 to 105 °C
	C			10 MHz		4.65	—		
	C			1 MHz		1.90	—		
	C			20 MHz	3	7.05	—		
	C			10 MHz		4.40	—		
	C			1 MHz		1.85	—		
2	C	Run supply current FBE mode, all modules off & gated; run from flash	RI <sub>DD</sub>	20 MHz	5	5.88	—	mA	-40 to 105 °C
	C			10 MHz		3.70	—		
	C			1 MHz		1.85	—		
	C			20 MHz	3	5.35	—		
	C			10 MHz		3.42	—		
	C			1 MHz		1.80	—		
3	P	Run supply current FBE mode, all modules on; run from RAM	RI <sub>DD</sub>	20 MHz	5	10.9	14.0	mA	-40 to 105 °C
	C			10 MHz		6.10	—		
	C			1 MHz		1.69	—		
	P			20 MHz	3	8.18	—		
	C			10 MHz		5.14	—		
	C			1 MHz		1.44	—		
4	P	Run supply current FBE mode, all modules off & gated; run from RAM	RI <sub>DD</sub>	20 MHz	5	8.50	13.0	mA	-40 to 105 °C
	C			10 MHz		5.07	—		
	C			1 MHz		1.59	—		
	P			20 MHz	3	6.11	—		
	C			10 MHz		4.10	—		
	C			1 MHz		1.34	—		
5	P	Wait mode current FEI mode, all modules on	WI <sub>DD</sub>	20 MHz	5	5.95	—	mA	-40 to 105 °C
	C			10 MHz		3.50	—		
	C			1 MHz		1.24	—		
	P			20 MHz	3	5.45	—		
	C			10 MHz		3.25	—		
	C			1 MHz		1.20	—		
6	C	Stop3 mode supply current no clocks active (except 1kHz LPO clock) <sup>2, 3</sup>	S3I <sub>DD</sub>	—	5	4.6	—	µA	-40 to 105 °C
	C			—	3	4.5	—		-40 to 105 °C
7	C	ADC adder to stop3	—	—	5	40	—	µA	-40 to 105 °C

Table continues on the next page...

## 5.2 Switching specifications

### 5.2.1 Control timing

Table 6. Control timing

Num	C	Rating		Symbol	Min	Typical <sup>1</sup>	Max	Unit
1	P	Bus frequency ( $t_{cyc} = 1/f_{Bus}$ )		$f_{Bus}$	DC	—	20	MHz
2	C	Internal low power oscillator frequency		$f_{LPO}$	—	1.0	—	KHz
3	D	External reset pulse width <sup>2</sup>		$t_{extrst}$	$1.5 \times t_{cyc}$	—	—	ns
4	D	Reset low drive		$t_{rstdrv}$	$34 \times t_{cyc}$	—	—	ns
5	D	BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes		$t_{MSSU}$	500	—	—	ns
6	D	BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes <sup>3</sup>		$t_{MSH}$	100	—	—	ns
7	D	IRQ pulse width	Asynchronous path <sup>2</sup>	$t_{ILIH}$	100	—	—	ns
	D		Synchronous path <sup>4</sup>	$t_{IHIL}$	$1.5 \times t_{cyc}$	—	—	ns
8	D	Keyboard interrupt pulse width	Asynchronous path <sup>2</sup>	$t_{ILIH}$	100	—	—	ns
	D		Synchronous path	$t_{IHIL}$	$1.5 \times t_{cyc}$	—	—	ns
9	C	Port rise and fall time - standard drive strength (load = 50 pF) <sup>5</sup>	—	$t_{Rise}$	—	10.2	—	ns
	C			$t_{Fall}$	—	9.5	—	ns
	C	Port rise and fall time - high drive strength (load = 50 pF) <sup>5</sup>	—	$t_{Rise}$	—	5.4	—	ns
	C			$t_{Fall}$	—	4.6	—	ns

1. Typical values are based on characterization data at  $V_{DD} = 5.0$  V, 25 °C unless otherwise stated.
2. This is the shortest pulse that is guaranteed to be recognized as a reset pin request.
3. To enter BDM mode following a POR, BKGD/MS must be held low during the powerup and for a hold time of  $t_{MSH}$  after  $V_{DD}$  rises above  $V_{LVD}$ .
4. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized.
5. Timing is shown with respect to 20%  $V_{DD}$  and 80%  $V_{DD}$  levels. Temperature range -40 °C to 105 °C.

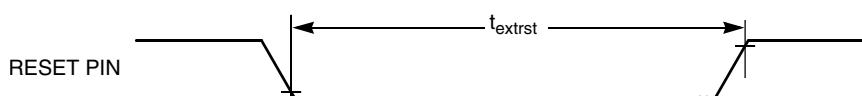


Figure 9. Reset timing

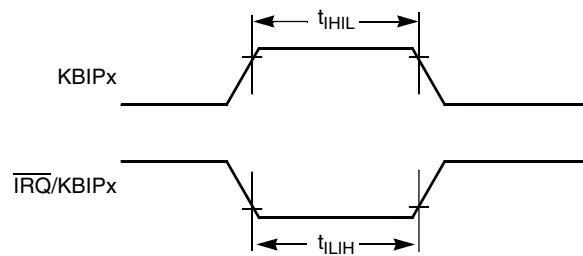


Figure 10. IRQ/KBIPx timing

## 5.2.2 Debug trace timing specifications

Table 7. Debug trace operating behaviors

Symbol	Description	Min.	Max.	Unit
$t_{\text{cyc}}$	Clock period		Frequency dependent	MHz
$t_{\text{wl}}$	Low pulse width	2	—	ns
$t_{\text{wh}}$	High pulse width	2	—	ns
$t_r$	Clock and data rise time	—	3	ns
$t_f$	Clock and data fall time	—	3	ns
$t_s$	Data setup	3	—	ns
$t_h$	Data hold	2	—	ns

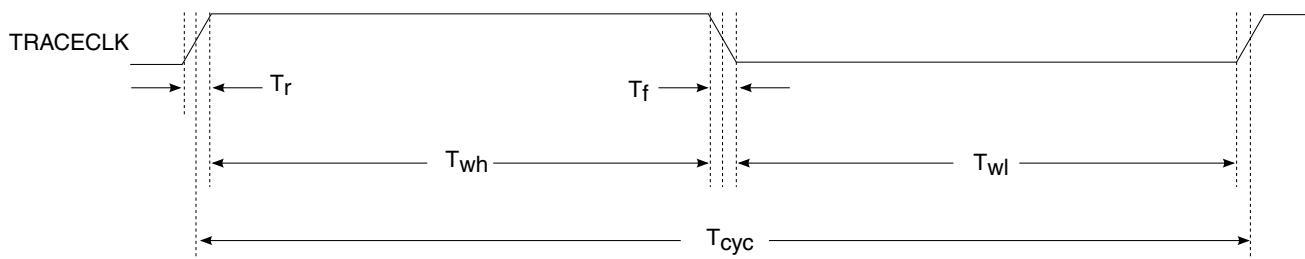


Figure 11. TRACE\_CLKOUT specifications

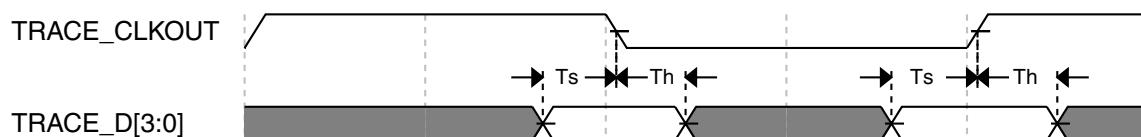


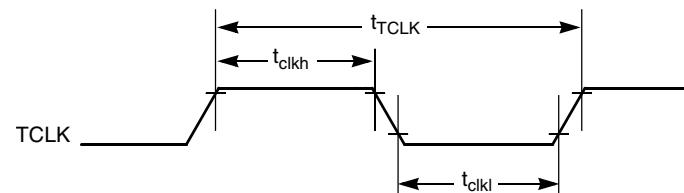
Figure 12. Trace data specifications

### 5.2.3 FTM module timing

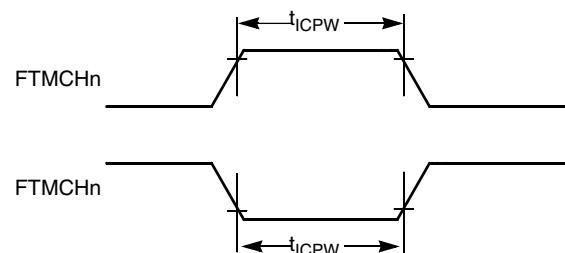
Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

**Table 8. FTM input timing**

No.	C	Function	Symbol	Min	Max	Unit
1	D	External clock frequency	$f_{TCLK}$	0	$f_{Bus}/4$	Hz
2	D	External clock period	$t_{TCLK}$	4	—	$t_{cyc}$
3	D	External clock high time	$t_{clkh}$	1.5	—	$t_{cyc}$
4	D	External clock low time	$t_{clkl}$	1.5	—	$t_{cyc}$
5	D	Input capture pulse width	$t_{ICPW}$	1.5	—	$t_{cyc}$



**Figure 13. Timer external clock**



**Figure 14. Timer input capture pulse**

## 5.3 Thermal specifications

### 5.3.1 Thermal characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take  $P_{I/O}$  into account in power calculations, determine the difference between actual pin voltage and  $V_{SS}$  or  $V_{DD}$  and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and  $V_{SS}$  or  $V_{DD}$  will be very small.

**Table 9. Thermal characteristics**

Rating	Symbol	Value	Unit
Operating temperature range (packaged)	$T_A^1$	$T_L$ to $T_H$ -40 to 105	°C
Junction temperature range	$T_J$	-40 to 150	°C
Thermal resistance single-layer board			
44-pin LQFP	$R_{\theta JA}$	76	°C/W
32-pin LQFP	$R_{\theta JA}$	88	°C/W
20-pin SOIC	$R_{\theta JA}$	82	°C/W
20-pin TSSOP	$R_{\theta JA}$	116	°C/W
16-pin TSSOP	$R_{\theta JA}$	130	°C/W
Thermal resistance four-layer board			
44-pin LQFP	$R_{\theta JA}$	54	°C/W
32-pin LQFP	$R_{\theta JA}$	59	°C/W
20-pin SOIC	$R_{\theta JA}$	54	°C/W
20-pin TSSOP	$R_{\theta JA}$	76	°C/W
16-pin TSSOP	$R_{\theta JA}$	87	°C/W

1. Maximum  $T_A$  can be exceeded only if the user ensures that  $T_J$  does not exceed the maximum. The simplest method to determine  $T_J$  is:  $T_J = T_A + R_{\theta JA} \times \text{chip power dissipation}$ .

## 6 Peripheral operating requirements and behaviors

## 6.1 External oscillator (XOSC) and ICS characteristics

**Table 10. XOSC and ICS specifications (temperature range = -40 to 105 °C ambient)**

Num	C	Characteristic		Symbol	Min	Typical <sup>1</sup>	Max	Unit
1	C	Oscillator crystal or resonator	Low range (RANGE = 0)	$f_{lo}$	31.25	32.768	39.0625	kHz
	C		High range (RANGE = 1) FEE or FBE mode <sup>2</sup>	$f_{hi}$	4	—	20	MHz
	C		High range (RANGE = 1), high gain (HGO = 1), FBELP mode	$f_{hi}$	4	—	20	MHz
	C		High range (RANGE = 1), low power (HGO = 0), FBELP mode	$f_{hi}$	4	—	20	MHz
2	D	Load capacitors		C1, C2	See Note <sup>3</sup>			
3	D	Feedback resistor	Low Frequency, Low-Power Mode <sup>4</sup>	$R_F$	—	—	—	MΩ
			Low Frequency, High-Gain Mode		—	10	—	MΩ
			High Frequency, Low-Power Mode		—	1	—	MΩ
			High Frequency, High-Gain Mode		—	1	—	MΩ
4	D	Series resistor - Low Frequency	Low-Power Mode <sup>4</sup>	$R_S$	—	—	—	kΩ
			High-Gain Mode		—	200	—	kΩ
5	D	Series resistor - High Frequency	Low-Power Mode <sup>4</sup>	$R_S$	—	—	—	kΩ
	D	Series resistor - High Frequency, High-Gain Mode	4 MHz		—	0	—	kΩ
	D		8 MHz		—	0	—	kΩ
	D		16 MHz		—	0	—	kΩ
6	C	Crystal start-up time Low range = 32.768 kHz crystal; High range = 20 MHz crystal <sup>5, 6</sup>	Low range, low power	$t_{CSTL}$	—	1000	—	ms
	C		Low range, high power		—	800	—	ms
	C		High range, low power	$t_{CSTH}$	—	3	—	ms
	C		High range, high power		—	1.5	—	ms
7	T	Internal reference start-up time		$t_{IRST}$	—	20	50	μs
8	D	Square wave input clock frequency	FEE or FBE mode <sup>2</sup>	$f_{extal}$	0.03125	—	5	MHz
	D		FBELP mode		0	—	20	MHz
9	P	Average internal reference frequency - trimmed		$f_{int\_t}$	—	31.25	—	kHz
10	P	DCO output frequency range - trimmed		$f_{dco\_t}$	16	—	20	MHz
11	P	Total deviation of DCO output from trimmed frequency <sup>5</sup>	Over full voltage and temperature range	$\Delta f_{dco\_t}$	—	—	±2.0	% $f_{dco}$
	C		Over fixed voltage and temperature range of 0 to 70 °C		—	—	±1.0	
12	C	FLL acquisition time <sup>5, 7</sup>		$t_{Acquire}$	—	—	2	ms

Table continues on the next page...

**Table 11. Flash characteristics (continued)**

C	Characteristic	Symbol	Min <sup>1</sup>	Typical <sup>2</sup>	Max <sup>3</sup>	Unit <sup>4</sup>
D	NVM Bus frequency	f <sub>NVMBUS</sub>	1	—	25	MHz
D	NVM Operating frequency	f <sub>NVMOP</sub>	0.8	1	1.05	MHz
D	Erase Verify All Blocks	t <sub>VFYALL</sub>	—	—	17338	t <sub>cyc</sub>
D	Erase Verify Flash Block	t <sub>RD1BLK</sub>	—	—	16913	t <sub>cyc</sub>
D	Erase Verify EEPROM Block	t <sub>RD1BLK</sub>	—	—	810	t <sub>cyc</sub>
D	Erase Verify Flash Section	t <sub>RD1SEC</sub>	—	—	484	t <sub>cyc</sub>
D	Erase Verify EEPROM Section	t <sub>DRD1SEC</sub>	—	—	555	t <sub>cyc</sub>
D	Read Once	t <sub>RDONCE</sub>	—	—	450	t <sub>cyc</sub>
D	Program Flash (2 word)	t <sub>PGM2</sub>	0.12	0.12	0.29	ms
D	Program Flash (4 word)	t <sub>PGM4</sub>	0.20	0.21	0.46	ms
D	Program Once	t <sub>PGMONCE</sub>	0.20	0.21	0.21	ms
D	Program EEPROM (1 Byte)	t <sub>DPGM1</sub>	0.10	0.10	0.27	ms
D	Program EEPROM (2 Byte)	t <sub>DPGM2</sub>	0.17	0.18	0.43	ms
D	Program EEPROM (3 Byte)	t <sub>DPGM3</sub>	0.25	0.26	0.60	ms
D	Program EEPROM (4 Byte)	t <sub>DPGM4</sub>	0.32	0.33	0.77	ms
D	Erase All Blocks	t <sub>ERSALL</sub>	96.01	100.78	101.49	ms
D	Erase Flash Block	t <sub>ERSBLK</sub>	95.98	100.75	101.44	ms
D	Erase Flash Sector	t <sub>ERSPG</sub>	19.10	20.05	20.08	ms
D	Erase EEPROM Sector	t <sub>DERSPG</sub>	4.81	5.05	20.57	ms
D	Unsecure Flash	t <sub>UNSECU</sub>	96.01	100.78	101.48	ms
D	Verify Backdoor Access Key	t <sub>VFYKEY</sub>	—	—	464	t <sub>cyc</sub>
D	Set User Margin Level	t <sub>MLOADU</sub>	—	—	407	t <sub>cyc</sub>
C	FLASH Program/erase endurance T <sub>L</sub> to T <sub>H</sub> = -40 °C to 105 °C	n <sub>FLPE</sub>	10 k	100 k	—	Cycles
C	EEPROM Program/erase endurance TL to TH = -40 °C to 105 °C	n <sub>FLPE</sub>	50 k	500 k	—	Cycles
C	Data retention at an average junction temperature of T <sub>Javg</sub> = 85°C after up to 10,000 program/erase cycles	t <sub>D_ret</sub>	15	100	—	years

1. Minimum times are based on maximum f<sub>NVMOP</sub> and maximum f<sub>NVMBUS</sub>

2. Typical times are based on typical f<sub>NVMOP</sub> and maximum f<sub>NVMBUS</sub>

3. Maximum times are based on typical f<sub>NVMOP</sub> and typical f<sub>NVMBUS</sub> plus aging

4. t<sub>cyc</sub> = 1 / f<sub>NVMBUS</sub>

Program and erase operations do not require any special power sources other than the normal V<sub>DD</sub> supply. For more detailed information about program/erase operations, see the Memory section.

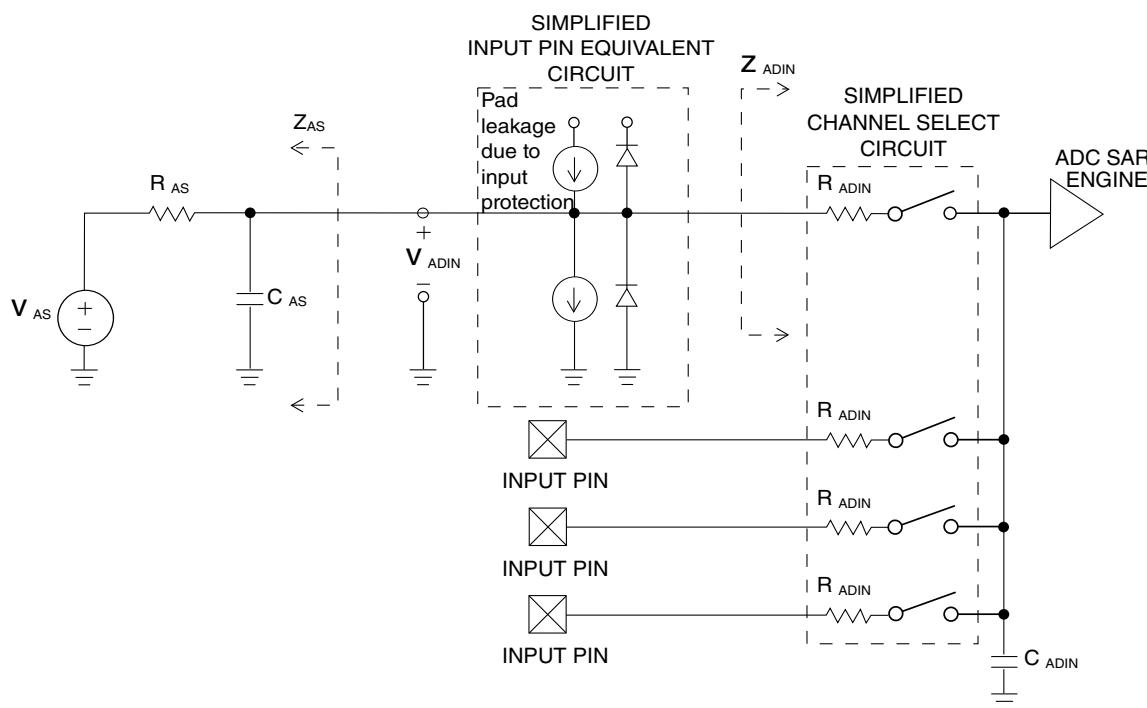


Figure 16. ADC input impedance equivalency diagram

Table 13. 12-bit ADC Characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )

Characteristic	Conditions	C	Symb	Min	Typ <sup>1</sup>	Max	Unit
Supply current ADLPC = 1 ADLSMP = 1 ADCO = 1		T	I <sub>DDA</sub>	—	133	—	µA
Supply current ADLPC = 1 ADLSMP = 0 ADCO = 1		T	I <sub>DDA</sub>	—	218	—	µA
Supply current ADLPC = 0 ADLSMP = 1 ADCO = 1		T	I <sub>DDA</sub>	—	327	—	µA
Supply current ADLPC = 0 ADLSMP = 0 ADCO = 1		T	I <sub>DDAD</sub>	—	582	990	µA
Supply current	Stop, reset, module off	T	I <sub>DDA</sub>	—	0.011	1	µA
ADC asynchronous clock source	High speed (ADLPC = 0)	P	f <sub>ADACK</sub>	2	3.3	5	MHz

Table continues on the next page...

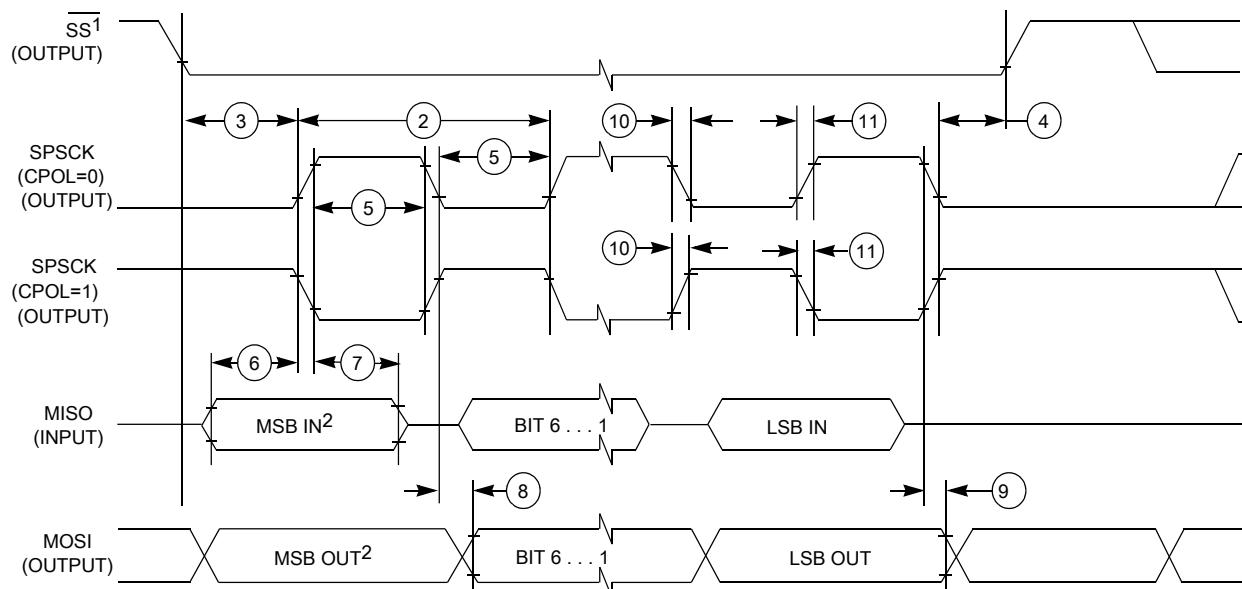
**Table 13. 12-bit ADC Characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ ) (continued)**

Characteristic	Conditions	C	Symb	Min	Typ <sup>1</sup>	Max	Unit
	Low power (ADLPC = 1)			1.25	2	3.3	
Conversion time (including sample time)	Short sample (ADLSMP = 0)	T	$t_{ADC}$	—	20	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	40	—	
Sample time	Short sample (ADLSMP = 0)	T	$t_{ADS}$	—	3.5	—	ADCK cycles
	Long sample (ADLSMP = 1)			—	23.5	—	
Total unadjusted Error <sup>2</sup>	12-bit mode	T	$E_{TUE}$	—	$\pm 5.0$	—	LSB <sup>3</sup>
	10-bit mode	P		—	$\pm 1.5$	$\pm 2.0$	
	8-bit mode	P		—	$\pm 0.7$	$\pm 1.0$	
Differential Non-Linearity	12-bit mode	T	DNL	—	$\pm 1.0$	—	LSB <sup>3</sup>
	10-bit mode <sup>4</sup>	P		—	$\pm 0.25$	$\pm 0.5$	
	8-bit mode <sup>4</sup>	P		—	$\pm 0.15$	$\pm 0.25$	
Integral Non-Linearity	12-bit mode	T	INL	—	$\pm 1.0$	—	LSB <sup>3</sup>
	10-bit mode	T		—	$\pm 0.3$	$\pm 0.5$	
	8-bit mode	T		—	$\pm 0.15$	$\pm 0.25$	
Zero-scale error <sup>5</sup>	12-bit mode	C	$E_{ZS}$	—	$\pm 2.0$	—	LSB <sup>3</sup>
	10-bit mode	P		—	$\pm 0.25$	$\pm 1.0$	
	8-bit mode	P		—	$\pm 0.65$	$\pm 1.0$	
Full-scale error <sup>6</sup>	12-bit mode	T	$E_{FS}$	—	$\pm 2.5$	—	LSB <sup>3</sup>
	10-bit mode	T		—	$\pm 0.5$	$\pm 1.0$	
	8-bit mode	T		—	$\pm 0.5$	$\pm 1.0$	
Quantization error	$\leq 12$ bit modes	D	$E_Q$	—	—	$\pm 0.5$	LSB <sup>3</sup>
Input leakage error <sup>7</sup>	all modes	D	$E_{IL}$	$I_{In} * R_{AS}$			mV
Temp sensor slope	-40°C– 25°C	D	m	—	3.266	—	mV/°C
	25°C– 125°C			—	3.638	—	
Temp sensor voltage	25°C	D	$V_{TEMP25}$	—	1.396	—	V

1. Typical values assume  $V_{DDA} = 5.0$  V, Temp = 25°C,  $f_{ADCK}=1.0$  MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
2. Includes quantization.
3. 1 LSB =  $(V_{REFH} - V_{REFL})/2^N$
4. Monotonicity and no-missing-codes guaranteed in 10-bit and 8-bit modes
5.  $V_{ADIN} = V_{SSA}$
6.  $V_{ADIN} = V_{DDA}$
7.  $I_{In}$  = leakage current (refer to DC characteristics)

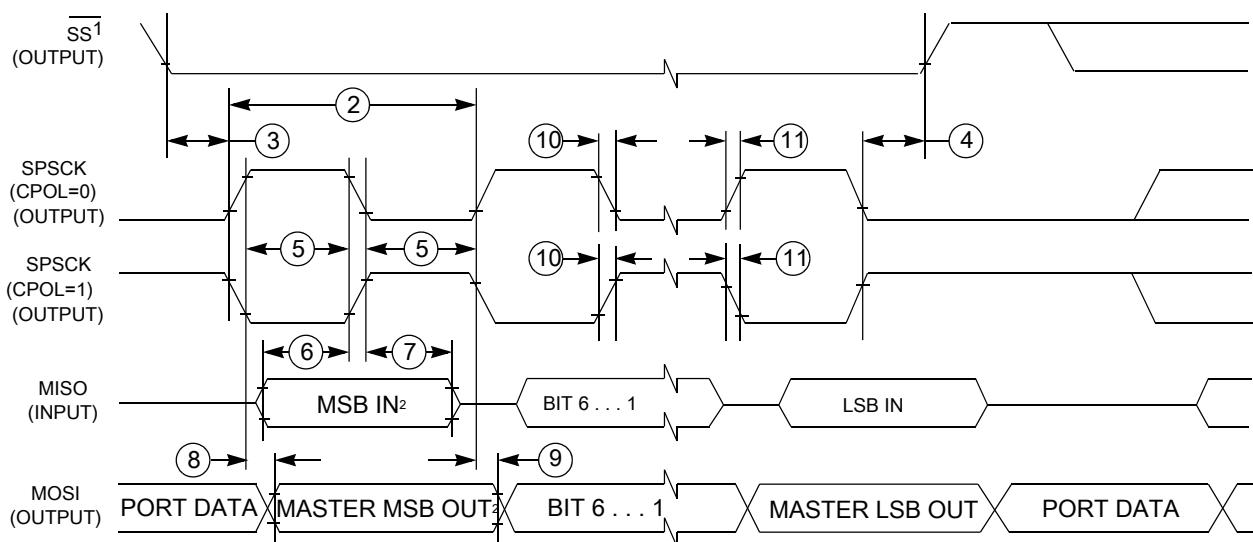
**Table 15. SPI master mode timing (continued)**

Nu. m.	Symbol	Description	Min.	Max.	Unit	Comment
	$t_{FI}$	Fall time input				
11	$t_{RO}$	Rise time output	—	25	ns	—
	$t_{FO}$	Fall time output				



1. If configured as an output.

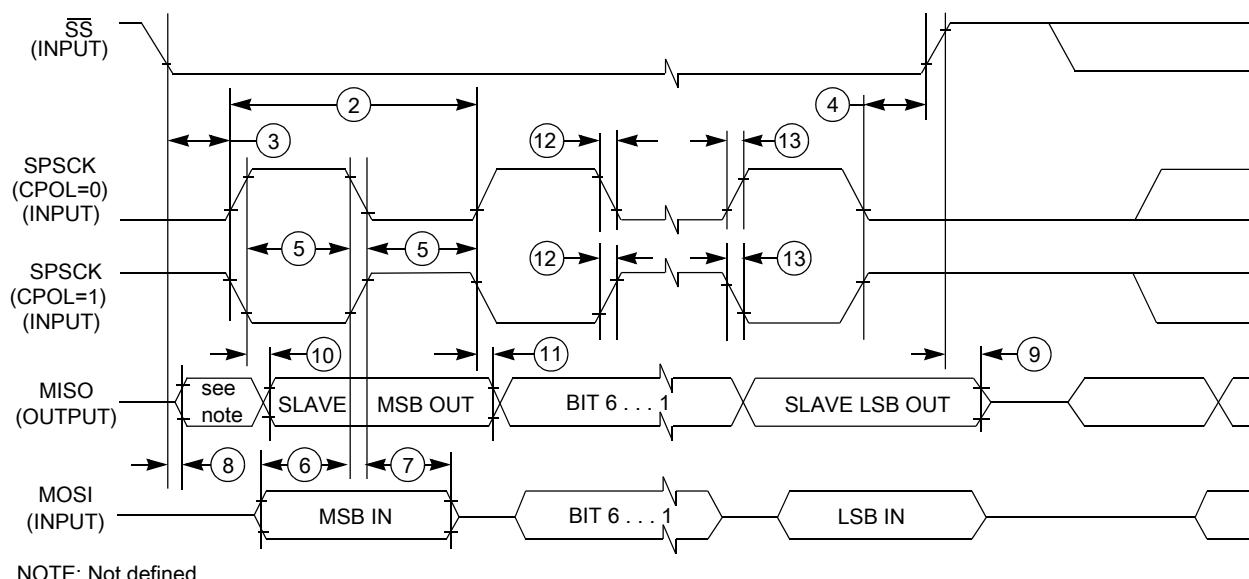
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 17. SPI master mode timing (CPHA=0)**

1. If configured as output

2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 18. SPI master mode timing (CPHA=1)**



**Figure 20. SPI slave mode timing (CPHA=1)**

## 7 Dimensions

### 7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to [freescale.com](http://freescale.com) and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
16-pin TSSOP	98ASH70247A
20-pin SOIC	98ASB42343B
20-pin TSSOP	98ASH70169A
32-pin LQFP	98ASH70029A
44-pin LQFP	98ASS23225W

## 8 Pinout

### 8.1 Signal multiplexing and pin assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

**Table 17. Pin availability by package pin-count**

Pin Number				Lowest Priority <--> Highest				
44-LQFP	32-LQFP	20-TSSOP	16-TSSOP	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
1	1	—	—	PTD1 <sup>1</sup>	—	FTM2CH3	—	—
2	2	—	—	PTD0 <sup>1</sup>	—	FTM2CH2	—	—
3	—	—	—	PTE4	—	TCLK2	—	—
4	—	—	—	PTE3	—	BUSOUT	—	—
5	3	3	3	—	—	—	—	V <sub>DD</sub>
6	4	—	—	—	—	—	V <sub>DDA</sub>	V <sub>REFH</sub>
7	5	—	—	—	—	—	V <sub>SSA</sub>	V <sub>REFL</sub>
8	6	4	4	—	—	—	—	V <sub>SS</sub>
9	7	5	5	PTB7	—	—	SCL	EXTAL
10	8	6	6	PTB6	—	—	SDA	XTAL
11	—	—	—	—	—	—	—	V <sub>ss</sub>
12	9	7	7	PTB5 <sup>1</sup>	—	FTM2CH5	SS0	—
13	10	8	8	PTB4 <sup>1</sup>	—	FTM2CH4	MISO0	—
14	11	9	—	PTC3	—	FTM2CH3	ADP11	—
15	12	10	—	PTC2	—	FTM2CH2	ADP10	—
16	—	—	—	PTD7	—	—	—	—
17	—	—	—	PTD6	—	—	—	—
18	—	—	—	PTD5	—	—	—	—
19	13	11	—	PTC1	—	FTM2CH1	ADP9	—
20	14	12	—	PTC0	—	FTM2CH0	ADP8	—
21	15	13	9	PTB3	KBI0P7	MOSI0	ADP7	—
22	16	14	10	PTB2	KBI0P6	SPSCK0	ADP6	—
23	17	15	11	PTB1	KBI0P5	TXD0	ADP5	—
24	18	16	12	PTB0	KBI0P4	RXD0	ADP4	—
25	19	—	—	PTA7	—	FTM2FAULT2	ADP3	—
26	20	—	—	PTA6	—	FTM2FAULT1	ADP2	—
27	—	—	—	—	—	—	—	V <sub>ss</sub>
28	—	—	—	—	—	—	—	V <sub>DD</sub>

Table continues on the next page...

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